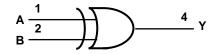


# SINGLE 2 INPUT EXCLUSIVE-OR GATE

## **Pin Descriptions**

Pin Name	Pin NO.	Description			
A	1	Data Input			
В	2	Data Input			
GND	3	Ground			
Y	4	Data Output			
V <sub>CC</sub>	5	Supply Voltage			

# Logic Diagram



## **Function Table**

Inp	Output	
Α	В	Y
Н	Н	L
L	Н	Н
Н	L	Н
L	L	L



# SINGLE 2 INPUT EXCLUSIVE-OR GATE

## Absolute Maximum Ratings (Note 2)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
V <sub>CC</sub>	Supply Voltage Range	-0.5 to 6.5	V
VI	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage applied to output in high or low state	-0.5 to V <sub>CC</sub> +0.5	V
I <sub>IK</sub>	Input Clamp Current VI<0	-20	mA
Ι <sub>ΟΚ</sub>	Output Clamp Current ( $V_O < 0$ or $V_O > V_{CC}$ )	±20	mA
Ι <sub>Ο</sub>	Continuous output current ( $V_O = 0$ to $V_{CC}$ )	±25	mA
I <sub>CC</sub>	Continuous current through V <sub>CC</sub>	50	mA
I <sub>GND</sub>	Continuous current through GND	-50	mA
TJ	Operating Junction Temperature	-40 to 150	°C
T <sub>STG</sub>	Storage Temperature	-65 to 150	°C

Notes: 2. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

## **Recommended Operating Conditions (Note 3)**

Symbol		Parameter	Min	Max	Unit
V <sub>CC</sub>	Operating Voltage		2	5.5	V
		$V_{CC} = 2V$	1.5		
VIH	High-level Input Voltage	$V_{CC} = 3V$	2.1		V
		$V_{CC} = 5.5V$	3.85		
		$V_{CC} = 2V$		0.5	
VIL	Low-level input voltage	$V_{CC} = 3V$		0.9	V
		$V_{CC} = 5.5V$		1.65	
VI	Input Voltage		0	5.5	V
Vo	Output Voltage		0	V <sub>CC</sub>	V
		$V_{CC} = 2V$		-50	uA
I <sub>OH</sub>	High-level output current	$V_{CC} = 3.3 V \pm 0.3 V$		-4	mA
		$V_{CC} = 5V \pm 0.5V$		-8	ША
		$V_{CC} = 2V$		50	uA
I <sub>OL</sub>	Low-level output current	$V_{CC} = 5V \pm 0.5V$		4	mA
		$V_{CC} = 3V$		8	MA
Δt/ΔV	Input transition rise or fall	$V_{CC} = 3.3V \pm 0.3V$		100	ns/V
Δι/Δν	rate	$V_{CC} = 5V \pm 0.5V$		20	ns/v
T <sub>A</sub>	Operating free-air temperature		-40	125	°C

Notes: 3. Unused inputs should be held at  $V_{CC}$  or Ground.



# SINGLE 2 INPUT EXCLUSIVE-OR GATE

## **Electrical Characteristics**

		<b>T</b>			25⁰C		-40ºC t	o 85⁰C	-40°C to	o 125⁰C	
Symbol	Symbol Parameter	Test Conditions	V <sub>CC</sub>	Min	Тур.	Max	Min	Max	Min	Max	Unit
		2V	1.9	2		1.9		1.9			
	High Level	I <sub>OH</sub> = -50μA	3V	2.9	3		2.9		2.9		
V <sub>OH</sub>	Output		4.5V	4.4	4.5		4.4		4.4		V
	Voltage	I <sub>OH</sub> = -4mA	3V	2.58			2.48		2.40		
		I <sub>OH</sub> = -8mA	4.5V	3.94			3.8		3.70		
			2V			0.1		0.1		0.1	
	Low Level	Ι <sub>ΟL</sub> = 50μΑ	3V			0.1		0.1		0.1	
V <sub>OL</sub>	Output		4.5V			0.1		0.1		0.1	V
	Voltage	$I_{OL} = 4mA$	3V			0.36		0.44		0.55	
		$I_{OL} = 8mA$	4.5V			0.36		0.44		0.55	
l <sub>l</sub>	Input Current	$V_I = 5.5 V \text{ or GND}$	0 to 5.5V			± 0.1		± 1		±2	μA
I <sub>CC</sub>	Supply Current	$V_1 = 5.5V \text{ or GND}$ $I_0=0$	5.5V			1		10		40	μA
Ci	Input Capacitance	$V_I = V_{CC} - or GND$	5.5V		2.0	10		10		10	pF
θ <sub>JA</sub>	Thermal Resistance	SOT25	(Note 4)		195						°C/W
UJA	Junction-to- Ambient	SOT353	(1006 4)		430						C/VV
_	Thermal Resistance	SOT25			58						
θ <sub>JC</sub>	Junction-to- Case	SOT353	(Note 4)		155						°C/W

Note: 4. Test conditions for SOT25, and SOT353: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout

### **Switching Characteristics**

#### V<sub>CC</sub> = 3.3V ± 0.3 (see Figure 1)

Doromotor	From	то			25⁰C		-40ºC t	o 85⁰C	-40°C to	o 125⁰C	Unit
Parameter	(Input)	(OUTPUT)		Min	Тур.	Max	Min	Max	Min	Max	Unit
	A or D	V	C <sub>L</sub> =15pF	0.6	4.0	11.0	0.6	13.0	0.6	14.0	ns
t <sub>pd</sub>	A or B	ř	$C_L=50pF$	0.6	5.8	14.5	0.6	16.5	0.6	18.5	ns

#### $V_{CC} = 5V \pm 0.5V$ (see Figure 1)

Parameter	From	то			25⁰C		-40ºC t	o 85⁰C	-40°C to	o 125⁰C	Unit
Parameter	(Input)	(OUTPUT)		Min	Тур.	Max	Min	Max	Min	Max	Unit
	A or B	V	C <sub>L</sub> =15pF	0.6	3.4	6.8	0.6	8.0	0.6	8.5	ns
٩d	AUP	ř	C <sub>L</sub> =50pF	0.6	4.9	8.8	0.6	10.0	0.6	11.5	ns



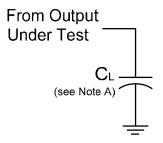
# SINGLE 2 INPUT EXCLUSIVE-OR GATE

## **Operating Characteristics**

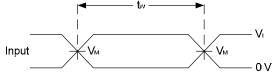
#### T<sub>A</sub> = 25 °C

	Parameter	Test Conditions	V <sub>CC</sub> = 5 V Typ.	Unit
C <sub>pd</sub>	Power dissipation capacitance	f = 1 MHz No Load	12	pF

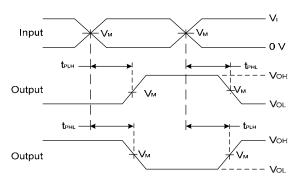
## Parameter Measurement Information



V	Inputs		V	<b>^</b>
V <sub>cc</sub>	VI	t <sub>r</sub> /t <sub>f</sub>	V <sub>M</sub>	CL
3.3V±0.3V	V <sub>CC</sub>	≤3ns	V <sub>CC</sub> /2	15pF
5V±0.5V	V <sub>CC</sub>	≤3ns	V <sub>CC</sub> /2	15pF
3.3V±0.3V	V <sub>CC</sub>	≤3ns	V <sub>CC</sub> /2	50pF
5V±0.5V	V <sub>CC</sub>	≤3ns	V <sub>CC</sub> /2	50pF



Voltage Waveform Pulse Duration



#### Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

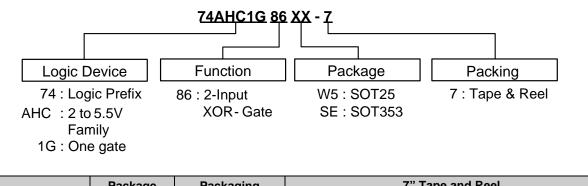
#### Figure 1. Load Circuit and Voltage Waveforms

- Notes: A. Includes test lead and test apparatus capacitance.
  - B. All pulses are supplied at pulse repetition rate  $\leq$  1 MHz.
    - C. Inputs are measured separately one transition per measurement.
    - D.  $t_{\mathsf{PLH}}$  and  $t_{\mathsf{PHL}}$  are the same as  $t_{\mathsf{PD.}}$



## SINGLE 2 INPUT EXCLUSIVE-OR GATE

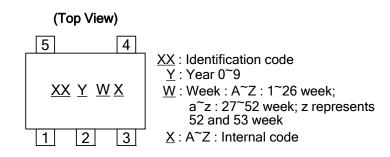
### **Ordering Information**



	Davias	Package	Packaging	7" Tape a	and Reel
	Device	Code	(Note 5)	Quantity	Part Number Suffix
<b>Pb</b> ,	74AHC1G86W5-7	W5	SOT25	3000/Tape & Reel	-7
<b>Pb</b> ,	74AHC1G86SE-7	SE	SOT353	3000/Tape & Reel	-7

Notes: 5. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

### **Marking Information**



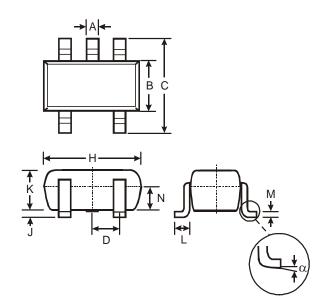
Part Number	Package	Identification Code
74AHC1G86W5	SOT25	YX
74AHC1G86SE	SOT353	ΥX



# SINGLE 2 INPUT EXCLUSIVE-OR GATE

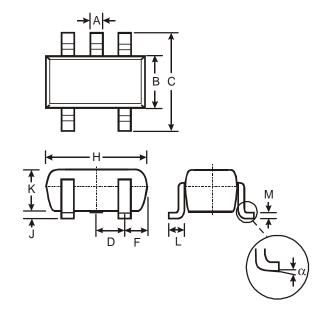
## Package Outline Dimensions (All Dimensions in mm)

### (1) Package Type: SOT25



	SOT25							
Dim	Тур							
Α	0.35	0.50	0.38					
В	1.50	1.70	1.60					
С	2.70	3.00	2.80					
D			0.95					
Н	2.90	3.10	3.00					
J	0.013	0.10	0.05					
Κ	1.00	1.30	1.10					
L	0.35	0.55	0.40					
Μ	0.10	0.20	0.15					
Ν	0.70	0.80	0.75					
α	0°	8°						
All D	imens	ions i	in mm					

### (2) Package Type: SOT353



SOT353		
Dim	Min	Max
Α	0.10	0.30
В	1.15	1.35
С	2.00	2.20
D	0.65 Тур	
F	0.40	0.45
Н	1.80	2.20
J	0	0.10
κ	0.90	1.00
L	0.25	0.40
Μ	0.10	0.22
α	0°	8°
All Dimensions in mm		



## SINGLE 2 INPUT EXCLUSIVE-OR GATE

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